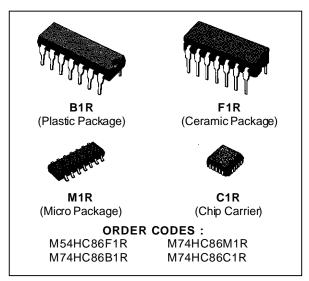


## QUAD EXCLUSIVE OR GATE

- HIGH SPEED
  - $t_{PD} = 10 \text{ ns} (TYP.) AT V_{CC} = 5 \text{ V}$
- LOW POWER DISSIPATION I<sub>CC</sub> = 1 μA (MAX.) AT T<sub>A</sub> = 25 °C
- HIGH NOISE IMMUNITY V<sub>NIH</sub> = V<sub>NIL</sub> = 28 % V<sub>CC</sub> (MIN.)
- OUTPUT DRIVE CAPABILITY 10 LSTTL LOADS
- SYMMETRICAL OUTPUT IMPEDANCE | I<sub>OH</sub> | = I<sub>OL</sub> = 4 mA (MIN.)
- BALANCED PROPAGATION DELAYS tplh = tphl
- WIDE OPERATING VOLTAGE RANGE V<sub>CC</sub> (OPR) = 2 V TO 6 V
- PIN AND FUNCTION COMPATIBLE WITH 54/74LS86



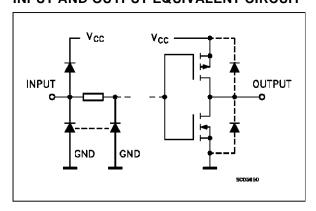
### **DESCRIPTION**

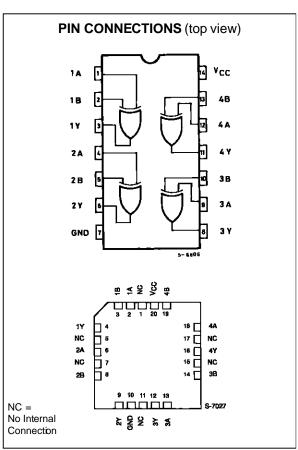
The M54/74HC86 is a high speed CMOS QUAD EXCLUSIVE OR GATE fabricated in silicon gate C<sup>2</sup>MOS technology.

It has the same high speed performance of LSTTL combined with true CMOS low power consumption. Input and output buffer are installed, which enables high noise immunity and stable output.

All inputs are equipped with protection circuits against static discharge and transient excess voltage.

### INPUT AND OUTPUT EQUIVALENT CIRCUIT





December 1992 1/9

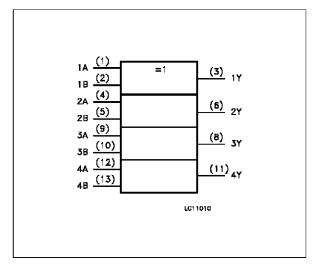
### **TRUTH TABLE**

| Α | В | Y |
|---|---|---|
| L | L | L |
| L | Н | Н |
| Н | L | Н |
| Н | Н | L |

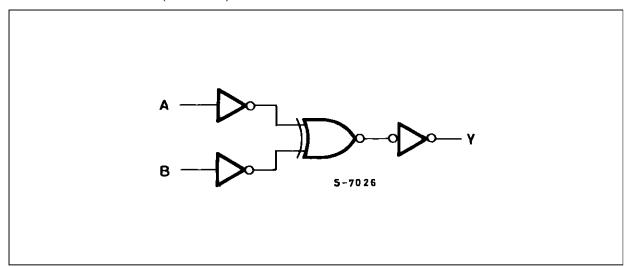
### **PIN DESCRIPTION**

| PIN No       | SYMBOL          | NAME AND FUNCTION       |
|--------------|-----------------|-------------------------|
| 1, 4, 9, 12  | 1A to 4A        | Data Inputs             |
| 2, 5, 10, 13 | 1B to 4B        | Data Inputs             |
| 3, 6, 8, 11  | 1Y to 4Y        | Data Outputs            |
| 7            | GND             | Ground (0V)             |
| 14           | V <sub>CC</sub> | Positive Supply Voltage |

### **IEC LOGIC SYMBOL**



### **SCHEMATIC CIRCUIT** (Per Gate)



### **ABSOLUTE MAXIMUM RATINGS**

| Symbol                 | Parameter                                    | Value                         | Unit |
|------------------------|--|-------------------------------|------|
| Vcc                    | Supply Voltage                               | -0.5 to +7                    | V    |
| $V_{I}$                | DC Input Voltage                             | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| Vo                     | DC Output Voltage                            | -0.5 to V <sub>CC</sub> + 0.5 | V    |
| l <sub>IK</sub>        | DC Input Diode Current                       | ± 20                          | mA   |
| I <sub>OK</sub>        | DC Output Diode Current                      | ± 20                          | mA   |
| lo                     | DC Output Source Sink Current Per Output Pin | ± 25                          | mA   |
| CC or I <sub>GND</sub> | DC V <sub>CC</sub> or Ground Current         | ± 50                          | mA   |
| $P_{D}$                | Power Dissipation                            | 500 (*)                       | mW   |
| T <sub>stg</sub>       | Storage Temperature                          | -65 to +150                   | °C   |
| TL                     | Lead Temperature (10 sec)                    | 300                           | °C   |

Absolute Maximum Ratings are those values beyond which damage to the device may occur. Functional operation under these condition is not implied. (\*) 500 mW: ≅ 65 °C derate to 300 mW by 10mW/°C: 65 °C to 85 °C



### RECOMMENDED OPERATING CONDITIONS

| Symbol                          | Parameter  | Value                    | Unit                      |    |
|---------------------------------|--|--------------------------|---------------------------|----|
| $V_{CC}$                        | Supply Voltage   |                          | 2 to 6                    | V  |
| $V_{I}$                         | Input Voltage  |                          | 0 to V <sub>CC</sub>      | V  |
| Vo                              | Output Voltage   |                          | 0 to V <sub>CC</sub>      | V  |
| $T_{op}$                        | Operating Temperature: <b>M54HC</b> Series <b>M74HC</b> Series |                          | -55 to +125<br>-40 to +85 | °C |
| t <sub>r</sub> , t <sub>f</sub> | Input Rise and Fall Time                                       | V <sub>CC</sub> = 2 V    | 0 to 1000                 | ns |
|                                 |  | $V_{CC} = 4.5 \text{ V}$ | 0 to 500                  |    |
|                                 |  | $V_{CC} = 6 V$           | 0 to 400                  |    |

## DC SPECIFICATIONS

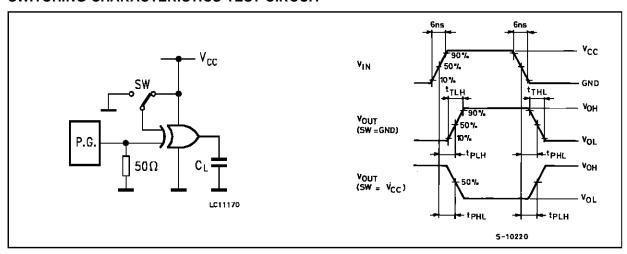
|          |                             | Te                  | est Co                              | nditions                | Value                                   |      |                      |      |                       |      |      |    |
|----------|-----------------------------|---------------------|-------------------------------------|-------------------------|---|------|----------------------|------|-----------------------|------|------|----|
| Symbol   | Parameter                   | V <sub>CC</sub> (V) |                                     |                         | T <sub>A</sub> = 25 °C<br>54HC and 74HC |      | -40 to 85 °C<br>74HC |      | -55 to 125 °C<br>54HC |      | Unit |    |
|          |                             | ( )                 |                                     |                         | Min.                                    | Тур. | Max.                 | Min. | Max.                  | Min. | Max. |    |
| $V_{IH}$ | High Level Input            | 2.0                 |                                     |                         | 1.5                                     |      |                      | 1.5  |                       | 1.5  |      |    |
|          | Voltage                     | 4.5                 |                                     |                         | 3.15                                    |      |                      | 3.15 |                       | 3.15 |      | V  |
|          |                             | 6.0                 |                                     |                         | 4.2                                     |      |                      | 4.2  |                       | 4.2  |      |    |
| $V_{IL}$ | Low Level Input             | 2.0                 |                                     |                         |   |      | 0.5                  |      | 0.5                   |      | 0.5  |    |
|          | Voltage                     | 4.5                 |                                     |                         |   |      | 1.35                 |      | 1.35                  |      | 1.35 | V  |
|          |                             | 6.0                 |                                     |                         |   |      | 1.8                  |      | 1.8                   |      | 1.8  |    |
| VoH      | High Level                  | 2.0                 | V <sub>I</sub> = V <sub>IH</sub> or | Ι <sub>Ο</sub> =-20 μΑ  | 1.9                                     | 2.0  |                      | 1.9  |                       | 1.9  |      | V  |
|          | Output Voltage              | 4.5                 |                                     |                         | 4.4                                     | 4.5  |                      | 4.4  |                       | 4.4  |      |    |
|          |                             | 6.0                 |                                     |                         | 5.9                                     | 6.0  |                      | 5.9  |                       | 5.9  |      |    |
|          |                             | 4.5                 | VIL                                 | I <sub>O</sub> =-4.0 mA | 4.18                                    | 4.31 |                      | 4.13 |                       | 4.10 |      |    |
|          |                             | 6.0                 |                                     | I <sub>O</sub> =-5.2 mA | 5.68                                    | 5.8  |                      | 5.63 |                       | 5.60 |      |    |
| $V_{OL}$ | Low Level Output            | 2.0                 | Vı =                                |                         |   | 0.0  | 0.1                  |      | 0.1                   |      | 0.1  |    |
|          | Voltage                     | 4.5                 | VI =                                | I <sub>O</sub> = 20 μA  |   | 0.0  | 0.1                  |      | 0.1                   |      | 0.1  |    |
|          |                             | 6.0                 | or                                  |                         |   | 0.0  | 0.1                  |      | 0.1                   |      | 0.1  | V  |
|          |                             | 4.5                 | V <sub>IL</sub>                     | I <sub>O</sub> = 4.0 mA |   | 0.17 | 0.26                 |      | 0.33                  |      | 0.40 |    |
|          |                             | 6.0                 |                                     | I <sub>O</sub> = 5.2 mA |   | 0.18 | 0.26                 |      | 0.33                  |      | 0.40 |    |
| I        | Input Leakage<br>Current    | 6.0                 | V <sub>I</sub> = '                  | V <sub>CC</sub> or GND  |   |      | ±0.1                 |      | ±1                    |      | ±1   | μΑ |
| Icc      | Quiescent Supply<br>Current | 6.0                 | V <sub>I</sub> = '                  | Vcc or GND              |   |      | 1                    |      | 10                    |      | 20   | μΑ |

### AC ELECTRICAL CHARACTERISTICS ( $C_L = 50 \text{ pF}$ , Input $t_r = t_f = 6 \text{ ns}$ )

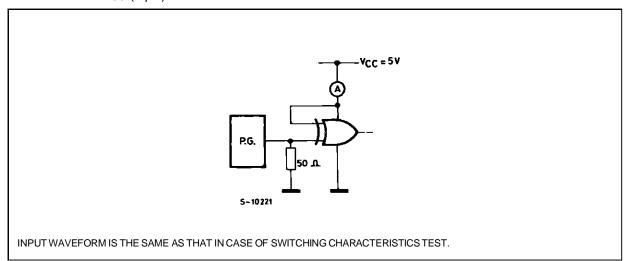
| Symbol Parameter    |                               | Test Conditions |  | Value |   |      |      |                      |      |                       |    |
|---------------------|-------------------------------|-----------------|--|-------|---|------|------|----------------------|------|-----------------------|----|
|                     |                               | Vcc             |  |       | T <sub>A</sub> = 25 °C<br>54HC and 74HC |      |      | -40 to 85 °C<br>74HC |      | -55 to 125 °C<br>54HC |    |
|                     |                               | (V)             |  | Min.  | Тур.                                    | Max. | Min. | Max.                 | Min. | Max.                  |    |
| t <sub>TLH</sub>    | Output Transition             | 2.0             |  |       | 30                                      | 75   |      | 95                   |      | 110                   |    |
| t <sub>THL</sub>    | Time                          | 4.5             |  |       | 8                                       | 15   |      | 19                   |      | 22                    | ns |
|                     |                               | 6.0             |  |       | 7                                       | 13   |      | 16                   |      | 19                    |    |
| t <sub>PLH</sub>    | Propagation                   | 2.0             |  |       | 56                                      | 110  |      | 140                  |      | 165                   |    |
| t <sub>PHL</sub>    | Delay Time                    | 4.5             |  |       | 14                                      | 22   |      | 28                   |      | 33                    | ns |
|                     |                               | 6.0             |  |       | 12                                      | 19   |      | 24                   |      | 28                    |    |
| C <sub>IN</sub>     | Input Capacitance             |                 |  |       | 5                                       | 10   |      | 10                   |      | 10                    | pF |
| C <sub>PD</sub> (*) | Power Dissipation Capacitance |                 |  |       | 26                                      |      |      |                      |      |                       | pF |

<sup>(\*)</sup> C<sub>PD</sub> is defined as the value of the IC's internal equivalent capacitance which is calculated from the operating current consumption without load. (Refer to Test Circuit). Average operting current can be obtained by the following equation. I<sub>CC</sub>(opr) = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>IN</sub> + I<sub>CC</sub>/4 (per Gate)

### SWITCHING CHARACTERISTICS TEST CIRCUIT



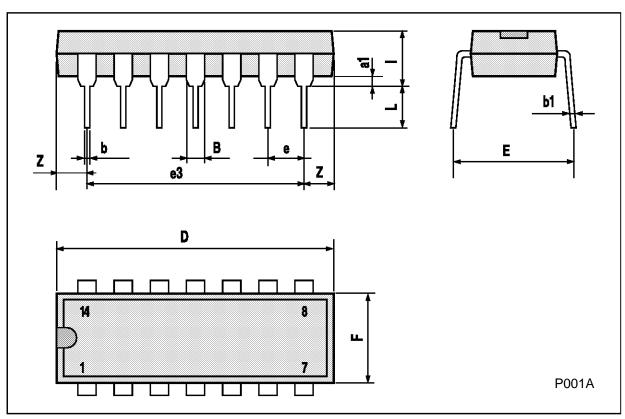
### TEST CIRCUIT Icc (Opr.)





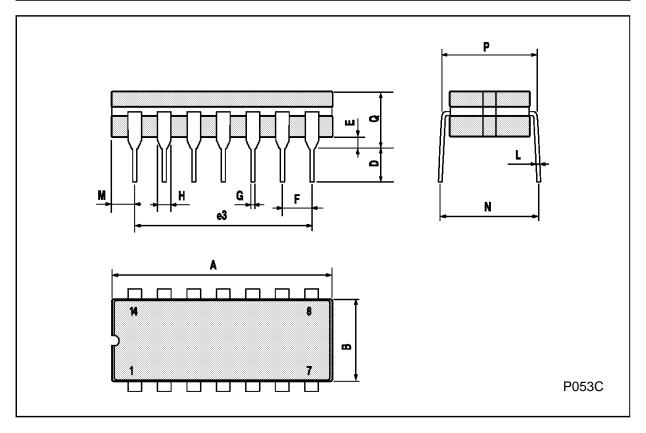
# Plastic DIP14 MECHANICAL DATA

| DIM.   |      | mm    |      | inch  |       |       |  |
|--------|------|-------|------|-------|-------|-------|--|
| Diiii. | MIN. | TYP.  | MAX. | MIN.  | TYP.  | MAX.  |  |
| a1     | 0.51 |       |      | 0.020 |       |       |  |
| В      | 1.39 |       | 1.65 | 0.055 |       | 0.065 |  |
| b      |      | 0.5   |      |       | 0.020 |       |  |
| b1     |      | 0.25  |      |       | 0.010 |       |  |
| D      |      |       | 20   |       |       | 0.787 |  |
| E      |      | 8.5   |      |       | 0.335 |       |  |
| е      |      | 2.54  |      |       | 0.100 |       |  |
| e3     |      | 15.24 |      |       | 0.600 |       |  |
| F      |      |       | 7.1  |       |       | 0.280 |  |
| I      |      |       | 5.1  |       |       | 0.201 |  |
| L      |      | 3.3   |      |       | 0.130 |       |  |
| Z      | 1.27 |       | 2.54 | 0.050 |       | 0.100 |  |



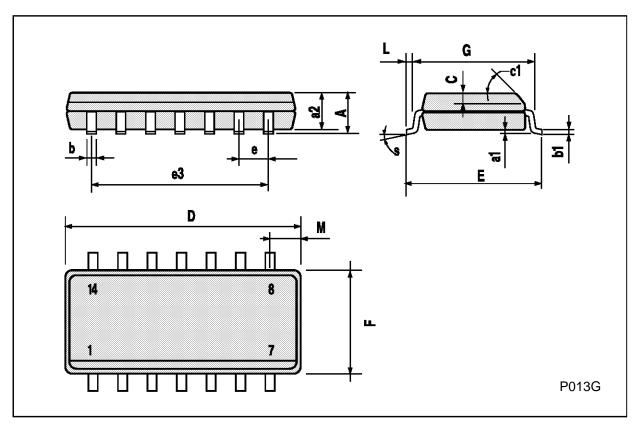
# **Ceramic DIP14/1 MECHANICAL DATA**

| DIM.  |      | mm    |      | inch  |       |       |  |
|-------|------|-------|------|-------|-------|-------|--|
| Diwi. | MIN. | TYP.  | MAX. | MIN.  | TYP.  | MAX.  |  |
| А     |      |       | 20   |       |       | 0.787 |  |
| В     |      |       | 7.0  |       |       | 0.276 |  |
| D     |      | 3.3   |      |       | 0.130 |       |  |
| Е     | 0.38 |       |      | 0.015 |       |       |  |
| e3    |      | 15.24 |      |       | 0.600 |       |  |
| F     | 2.29 |       | 2.79 | 0.090 |       | 0.110 |  |
| G     | 0.4  |       | 0.55 | 0.016 |       | 0.022 |  |
| H     | 1.17 |       | 1.52 | 0.046 |       | 0.060 |  |
| L     | 0.22 |       | 0.31 | 0.009 |       | 0.012 |  |
| М     | 1.52 |       | 2.54 | 0.060 |       | 0.100 |  |
| N     |      |       | 10.3 |       |       | 0.406 |  |
| Р     | 7.8  |       | 8.05 | 0.307 |       | 0.317 |  |
| Q     |      |       | 5.08 |       |       | 0.200 |  |



# **SO14 MECHANICAL DATA**

| DIM.   |      | mm   |       | inch   |       |       |  |  |
|--------|------|------|-------|--------|-------|-------|--|--|
| Dilwi. | MIN. | TYP. | MAX.  | MIN.   | TYP.  | MAX.  |  |  |
| А      |      |      | 1.75  |        |       | 0.068 |  |  |
| a1     | 0.1  |      | 0.2   | 0.003  |       | 0.007 |  |  |
| a2     |      |      | 1.65  |        |       | 0.064 |  |  |
| b      | 0.35 |      | 0.46  | 0.013  |       | 0.018 |  |  |
| b1     | 0.19 |      | 0.25  | 0.007  |       | 0.010 |  |  |
| С      |      | 0.5  |       |        | 0.019 |       |  |  |
| c1     |      |      | 45°   | (typ.) |       |       |  |  |
| D      | 8.55 |      | 8.75  | 0.336  |       | 0.344 |  |  |
| Е      | 5.8  |      | 6.2   | 0.228  |       | 0.244 |  |  |
| е      |      | 1.27 |       |        | 0.050 |       |  |  |
| e3     |      | 7.62 |       |        | 0.300 |       |  |  |
| F      | 3.8  |      | 4.0   | 0.149  |       | 0.157 |  |  |
| G      | 4.6  |      | 5.3   | 0.181  |       | 0.208 |  |  |
| L      | 0.5  |      | 1.27  | 0.019  |       | 0.050 |  |  |
| М      |      |      | 0.68  |        |       | 0.026 |  |  |
| S      |      |      | 8° (r | max.)  |       |       |  |  |



## PLCC20 MECHANICAL DATA

| DIM.   |      | mm   |       | inch  |       |       |  |  |
|--------|------|------|-------|-------|-------|-------|--|--|
| Diiii. | MIN. | TYP. | MAX.  | MIN.  | TYP.  | MAX.  |  |  |
| А      | 9.78 |      | 10.03 | 0.385 |       | 0.395 |  |  |
| В      | 8.89 |      | 9.04  | 0.350 |       | 0.356 |  |  |
| D      | 4.2  |      | 4.57  | 0.165 |       | 0.180 |  |  |
| d1     |      | 2.54 |       |       | 0.100 |       |  |  |
| d2     |      | 0.56 |       |       | 0.022 |       |  |  |
| E      | 7.37 |      | 8.38  | 0.290 |       | 0.330 |  |  |
| е      |      | 1.27 |       |       | 0.050 |       |  |  |
| e3     |      | 5.08 |       |       | 0.200 |       |  |  |
| F      |      | 0.38 |       |       | 0.015 |       |  |  |
| G      |      |      | 0.101 |       |       | 0.004 |  |  |
| М      |      | 1.27 |       |       | 0.050 |       |  |  |
| M1     |      | 1.14 |       |       | 0.045 |       |  |  |



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